



Vincotech

30-P2126PA140H7-L280F19Y

datasheet

flowPACK 2

1200 V / 140 A

Topology features

- 3xHalf Bridge
- Open Emitter configuration
- Kelvin Emitter for improved switching performance
- Temperature sensor

Component features

- High speed switching
- Low collector emitter saturation voltage
- Low turn-off losses
- Optimized for hard switching topologies
- Positive temperature coefficient

Housing features

- Base isolation: Al_2O_3
- Convex shaped baseplate for superior thermal contact
- Cu baseplate
- Thermo-mechanical push-and-pull force relief
- Press-fit pin
- Reliable cold welding connection

Target applications

- Elevator Drives
- Embedded Drives
- Industrial Drives

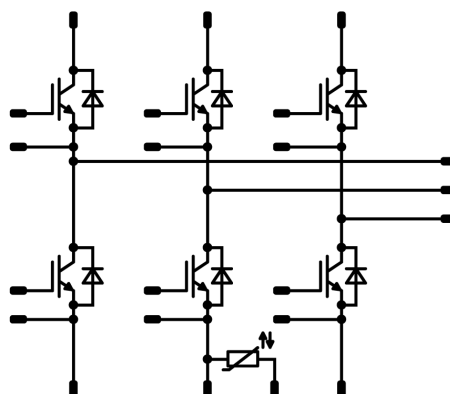
Types

- 30-P2126PA140H7-L280F19Y

flow 2 17 mm housing



Schematic





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Maximum Ratings

$T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_a = 80\text{ °C}$	121	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	420	A
Turn off safe operating area		$T_j = 150\text{ °C}$, $V_{CE} = 1200\text{ V}$	420	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_a = 80\text{ °C}$	231	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	°C

Inverter Diode

Peak repetitive reverse voltage	V_{RRM}		1200	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_a = 80\text{ °C}$	90	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	420	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_a = 80\text{ °C}$	169	W
Maximum junction temperature	T_{jmax}		175	°C

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	°C
Operation temperature under switching condition	T_{jop}		-40...+($T_{jmax} - 25$)	°C

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2\text{ s}$	6000	V
Creepage distance			>12,7	mm
Clearance			>12,7	mm
Comparative Tracking Index	CTI		≥ 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0012	25	4,7	5,5	6,2	V
Collector-emitter saturation voltage	V_{CEsat}		15		140	25 125 150		1,68 1,89 1,93	2,15 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			4	µA
Gate-emitter leakage current	I_{GES}		20	0		25			100	nA
Internal gate resistance	r_g							None		Ω
Input capacitance	C_{ies}	$f = 100 \text{ kHz}$	0	25		25		18500		pF
Output capacitance	C_{oes}							317		pF
Reverse transfer capacitance	C_{res}							94		pF
Gate charge	Q_g	$V_{CC} = 960 \text{ V}$	0/15		140	25		1032		nC

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,41		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	± 15	600	140	25 125 150		123,29 127,56 129,04		ns
Rise time	t_r					25 125 150		11,48 14,86 15,63		ns
Turn-off delay time	$t_{d(off)}$					25 125 150		145,1 176,64 184,83		ns
Fall time	t_f					25 125 150		33,18 59,5 67,06		ns
Turn-on energy (per pulse)	E_{on}					25 125 150		2,72 3,99 4,22		mWs
Turn-off energy (per pulse)	E_{off}					25 125 150		3,62 5,94 6,59		mWs



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	

Inverter Diode

Static

Forward voltage	V_F				36	25 125 150		1,74 1,44 1,37	2 ⁽¹⁾	V
Reverse leakage current	I_R	$V_i = 1200$ V				25			4	μA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						0,56		K/W
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Dynamic

Peak recovery current	I_{RM}	$di/dt=9135$ A/μs $di/dt=8755$ A/μs $di/dt=8690$ A/μs	± 15	600	140	25 125 150		163,78 220,09 233,26		A
Reverse recovery time	t_{rr}					25 125 150		35,06 55,53 62,67		ns
Recovered charge	Q_r					25 125 150		3,2 6,73 8,09		μC
Reverse recovered energy	E_{rec}					25 125 150		0,82 2,05 2,56		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		10250,71 8515,46 8263,89		A/μs



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	

Thermistor

Static

Rated resistance	R					25		22		kΩ
Deviation of R100	$\Delta_{R/R}$	$R_{100} = 1484 \Omega$				100	-5		5	%
Power dissipation	P					25		130		mW
Power dissipation constant	d					25		1,5		mW/K
B-value	$B_{(25/50)}$	Tol. $\pm 1 \%$						3962		K
B-value	$B_{(25/100)}$	Tol. $\pm 1 \%$						4000		K
Vincotech Thermistor Reference									I	

⁽¹⁾ Value at chip level

⁽²⁾ Only valid with pre-applied Vincotech thermal interface material.



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Inverter Switch Characteristics

figure 1. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

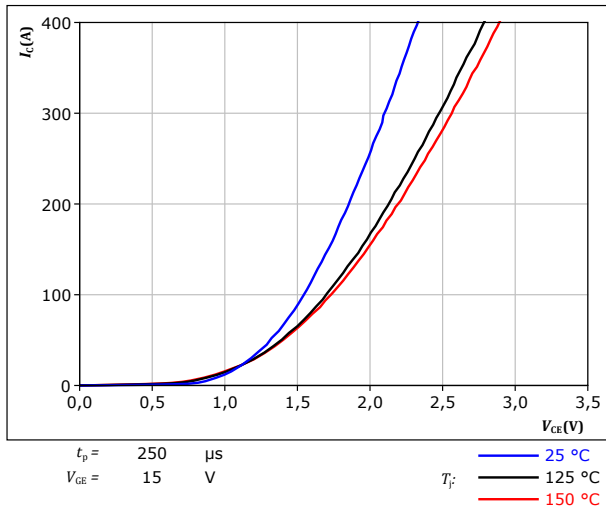


figure 2. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

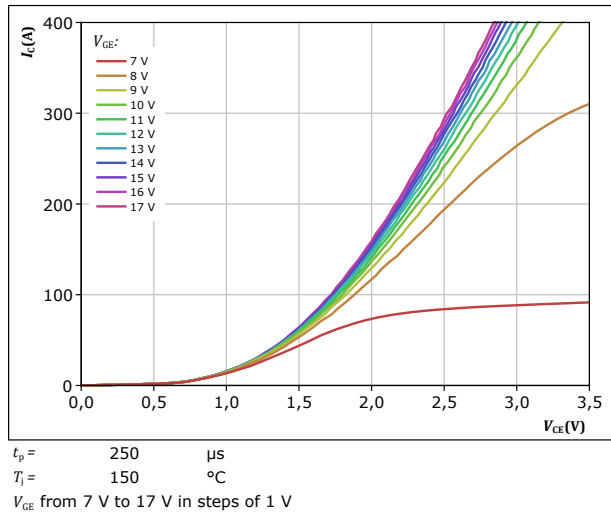


figure 3. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

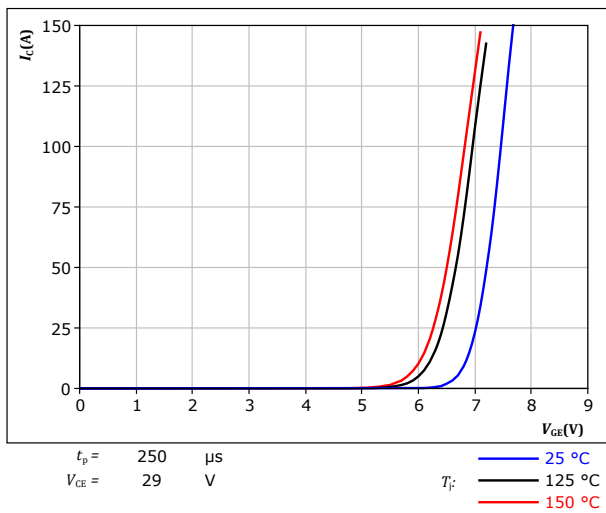
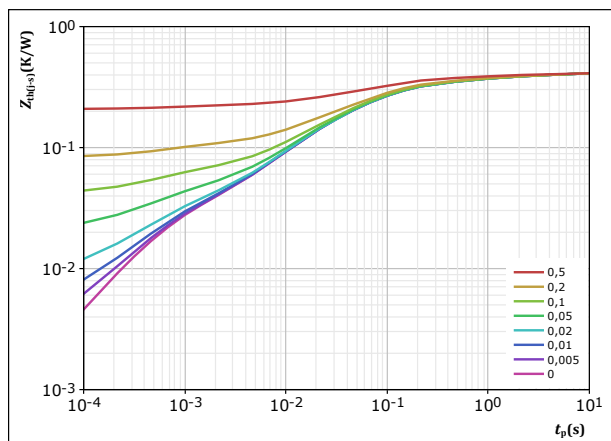


figure 4. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$





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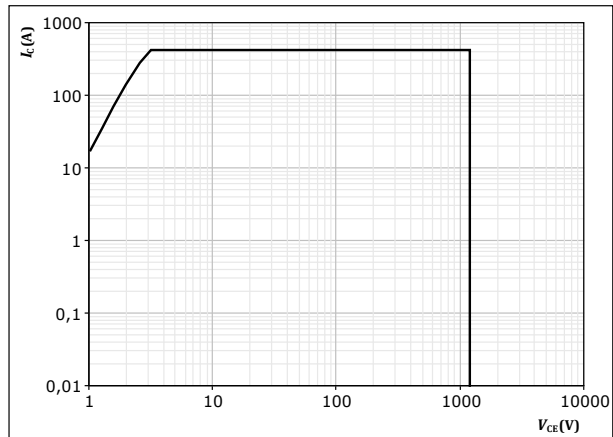
datasheet

Inverter Switch Characteristics

figure 5. IGBT

Safe operating area

$$I_C = f(V_{CE})$$

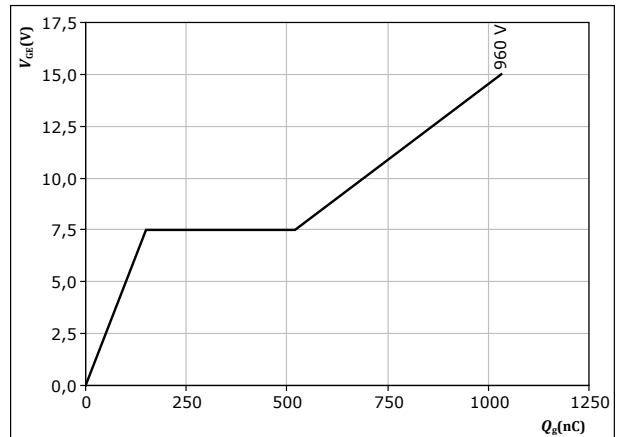


$D =$ single pulse
 $T_s = 80$ °C
 $V_{GE} = 15$ V
 $T_j = T_{jmax}$

figure 6. IGBT

Gate voltage vs gate charge

$$V_{GE} = f(Q_g)$$



$I_C = 140$ A
 $T_j = 25$ °C



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Inverter Diode Characteristics

figure 7.

FWD

Typical forward characteristics

$$I_F = f(V_F)$$

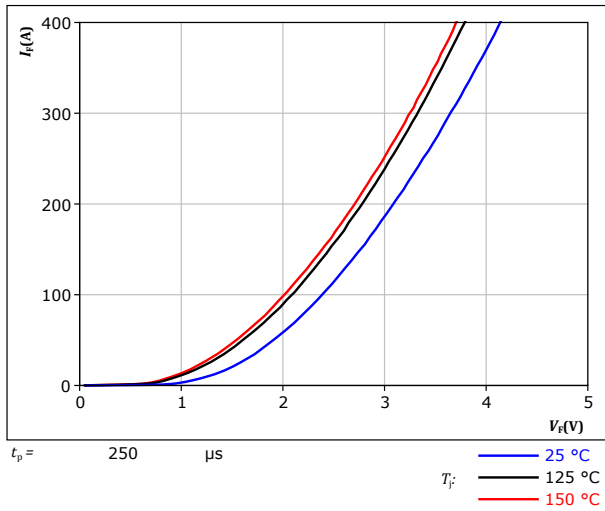
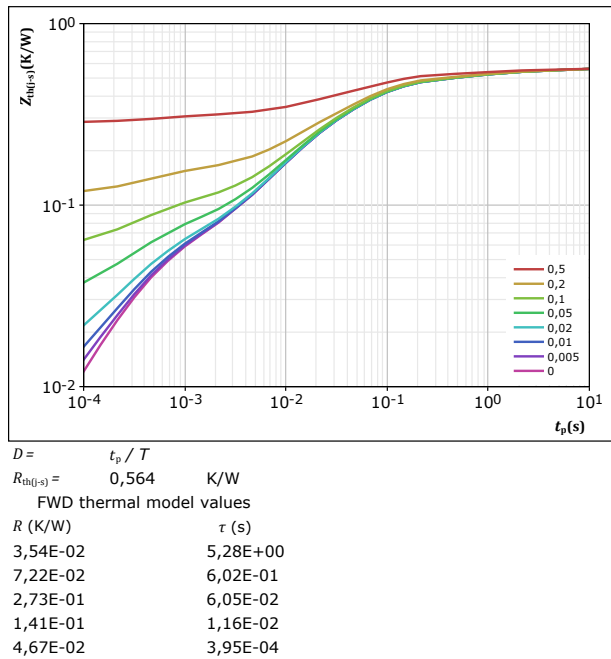


figure 8.

FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$





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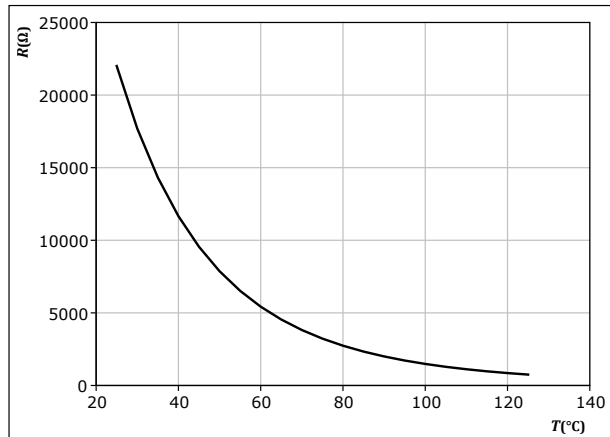
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Thermistor Characteristics

figure 9. Thermistor

Typical NTC characteristic as function of temperature

$$R_T = f(T)$$





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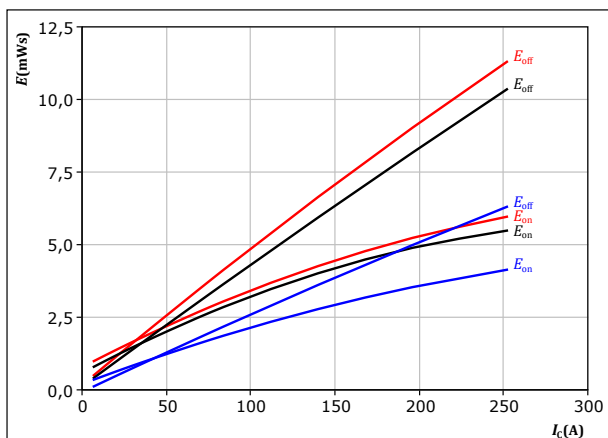
Inverter Switching Characteristics

figure 10.

IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_C)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω
 $R_{goff} = 2$ Ω

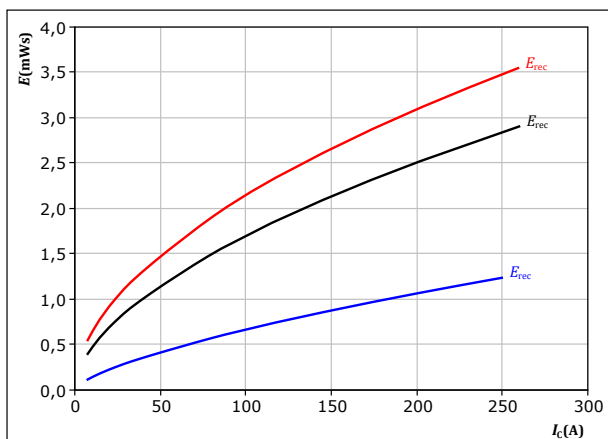
T_j : 25 °C
125 °C
150 °C

figure 12.

FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_C)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω

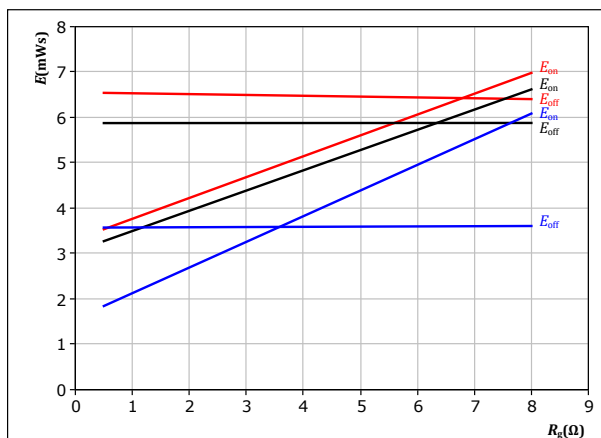
T_j : 25 °C
125 °C
150 °C

figure 11.

IGBT

Typical switching energy losses as a function of IGBT turn on gate resistor

$$E = f(R_g)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 140$ A

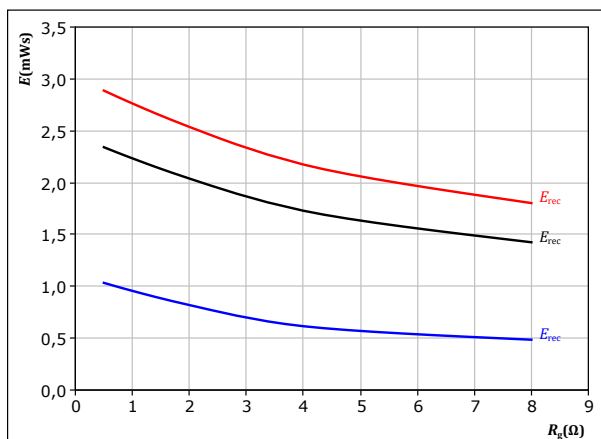
T_j : 25 °C
125 °C
150 °C

figure 13.

FWD

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 140$ A

T_j : 25 °C
125 °C
150 °C



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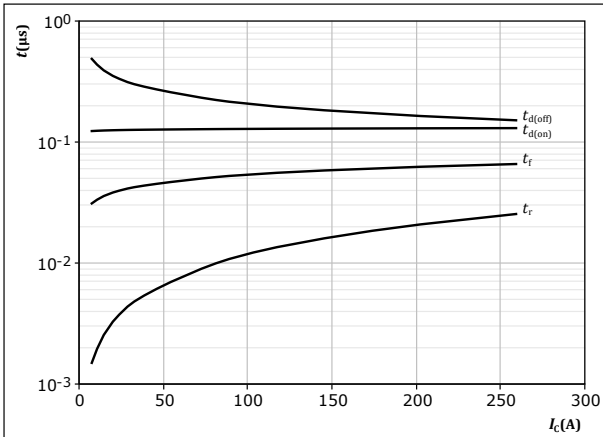
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Inverter Switching Characteristics

figure 14.

IGBT

Typical switching times as a function of collector current
 $t = f(I_C)$



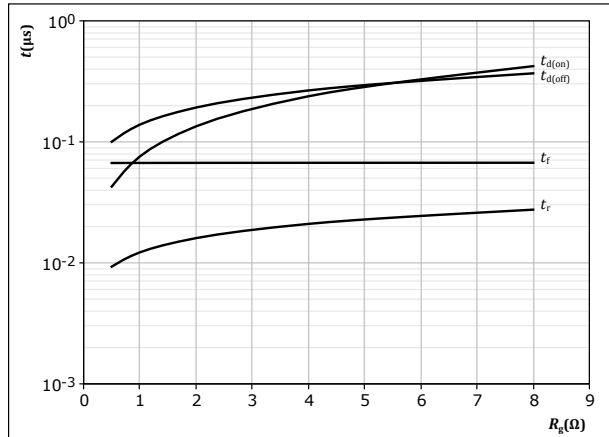
With an inductive load at

$T_j = 150$ °C
 $V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω
 $R_{goff} = 2$ Ω

figure 15.

IGBT

Typical switching times as a function of IGBT turn on gate resistor
 $t = f(R_g)$



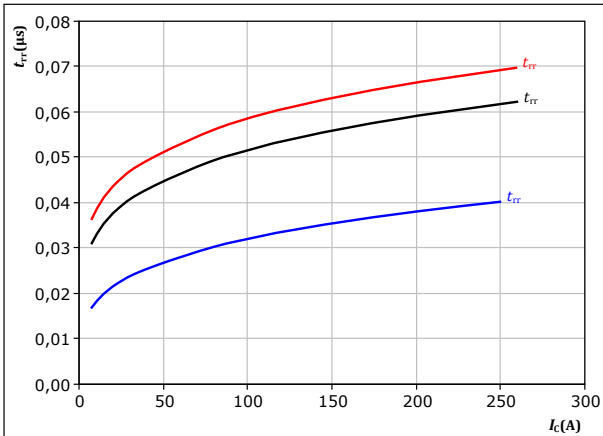
With an inductive load at

$T_j = 150$ °C
 $V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 140$ A

figure 16.

FWD

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$



With an inductive load at

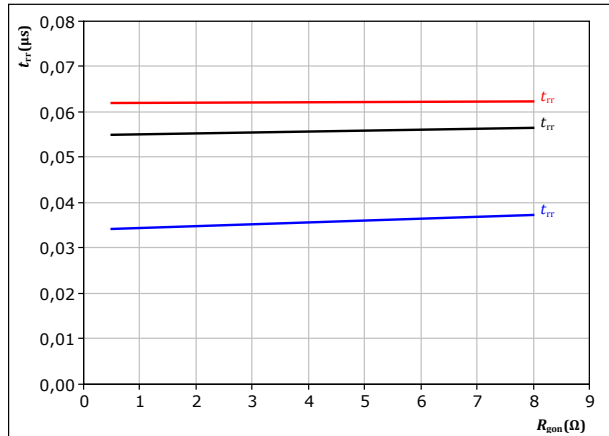
$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω

T_j : 25 °C
125 °C
150 °C

figure 17.

FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 140$ A

T_j : 25 °C
125 °C
150 °C



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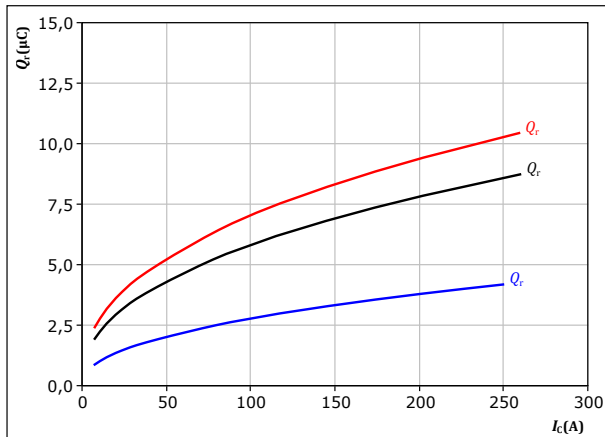
Inverter Switching Characteristics

figure 18.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω

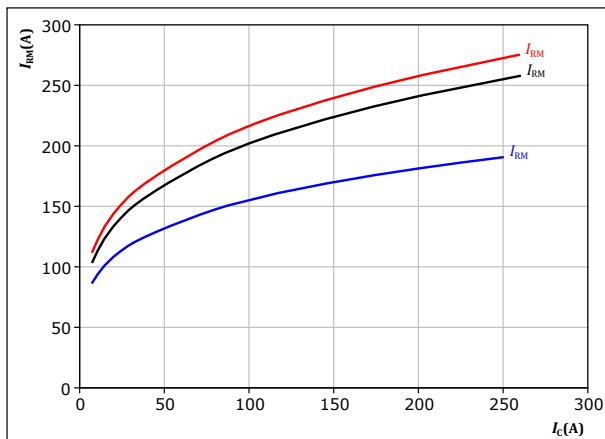
T_j : 25 °C
125 °C
150 °C

figure 20.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω

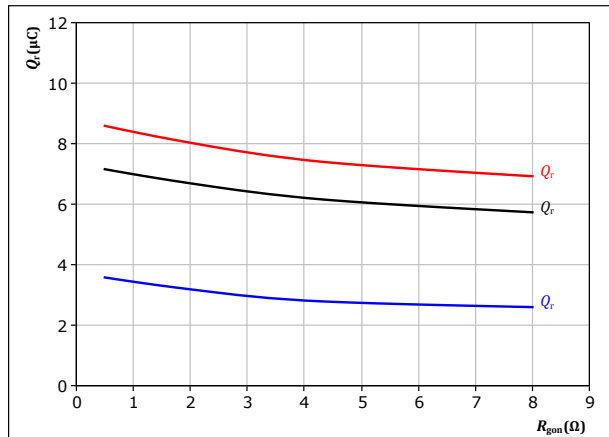
T_j : 25 °C
125 °C
150 °C

figure 19.

FWD

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 140$ A

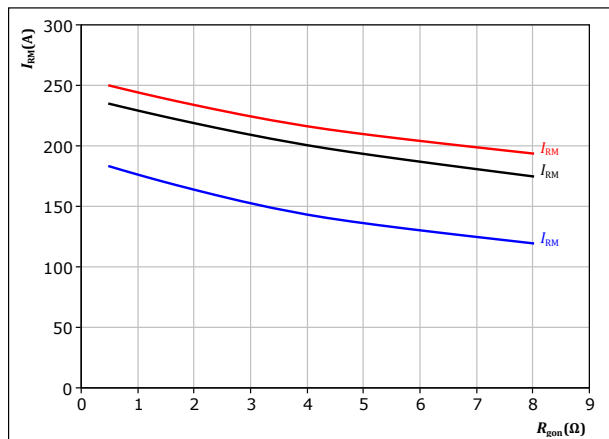
T_j : 25 °C
125 °C
150 °C

figure 21.

FWD

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 140$ A

T_j : 25 °C
125 °C
150 °C



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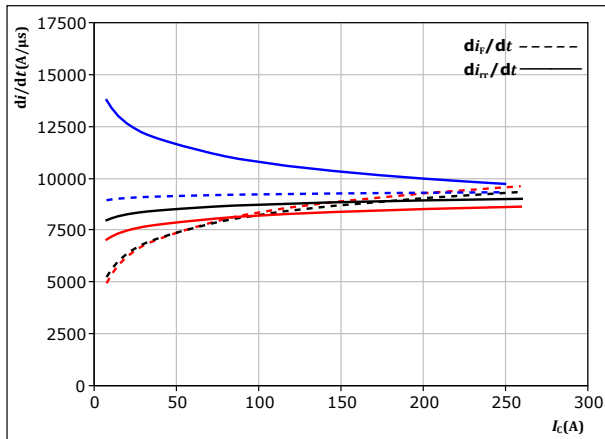
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datasheet

Inverter Switching Characteristics

figure 22. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_r/dt = f(I_C)$

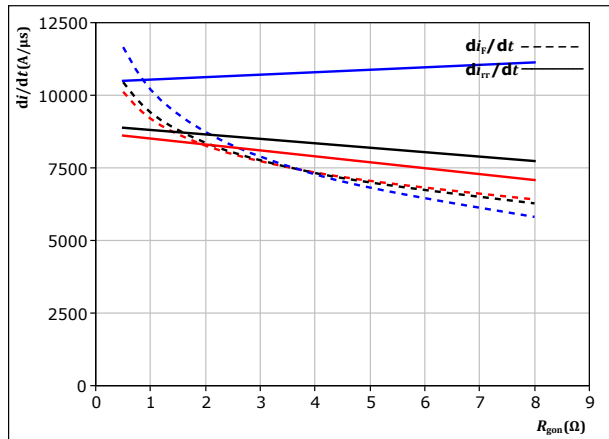


With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \text{ } \Omega$
 $T_j: 25 \text{ } ^\circ\text{C}$
 $125 \text{ } ^\circ\text{C}$
 $150 \text{ } ^\circ\text{C}$

figure 23. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_r/dt = f(R_{gon})$



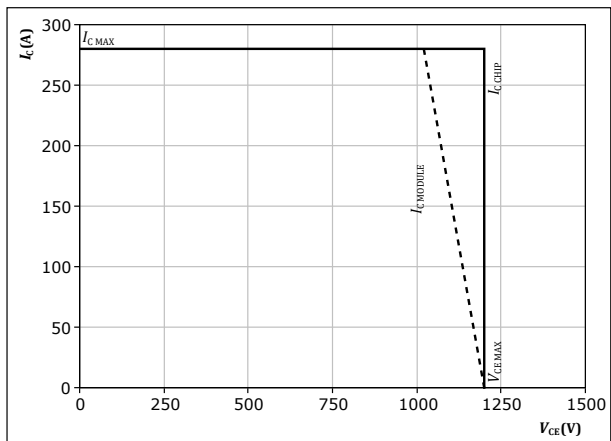
With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 140 \text{ A}$
 $T_j: 25 \text{ } ^\circ\text{C}$
 $125 \text{ } ^\circ\text{C}$
 $150 \text{ } ^\circ\text{C}$

figure 24. IGBT

Reverse bias safe operating area

$I_C = f(V_{CE})$



At $T_j = 150 \text{ } ^\circ\text{C}$
 $R_{gon} = 2 \text{ } \Omega$
 $R_{goff} = 2 \text{ } \Omega$



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Inverter Switching Definitions

figure 25. IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

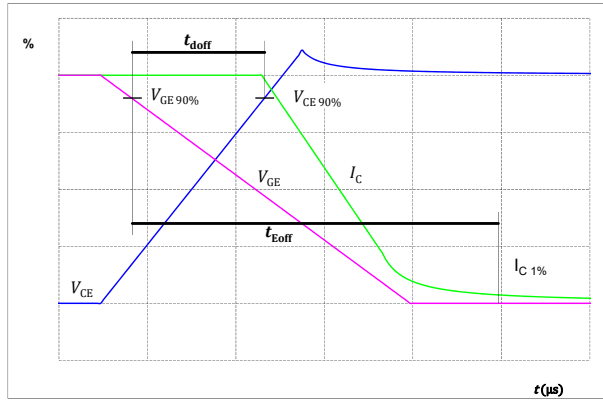


figure 26. IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

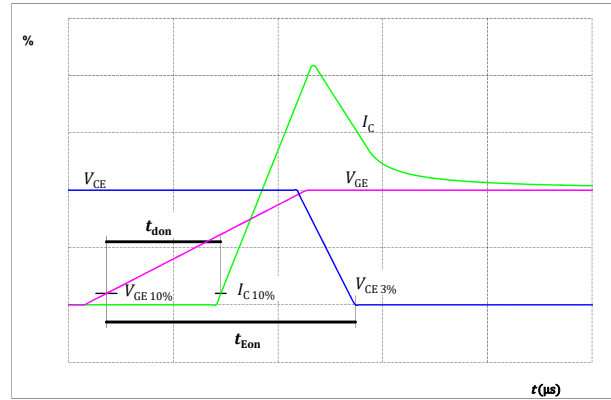


figure 27. IGBT

Turn-off Switching Waveforms & definition of t_f

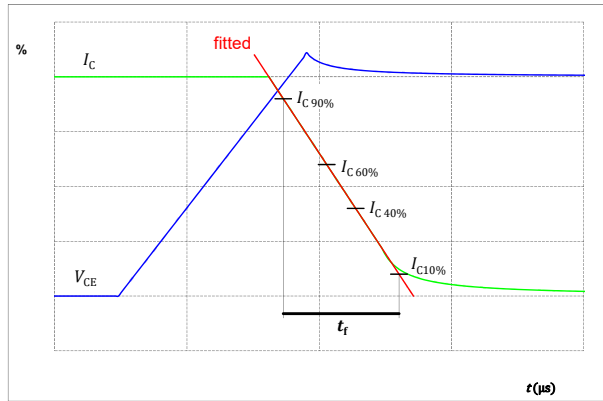
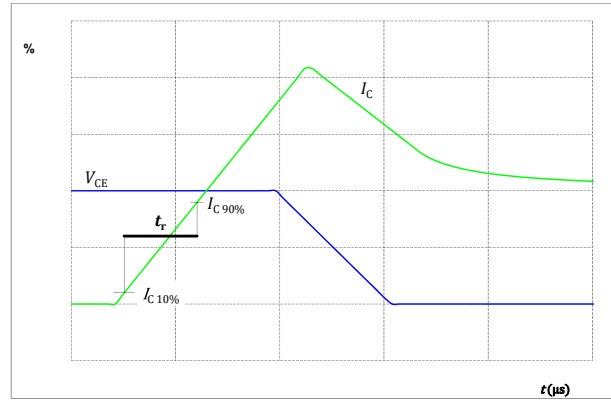


figure 28. IGBT

Turn-on Switching Waveforms & definition of t_r





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Inverter Switching Definitions

figure 29.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

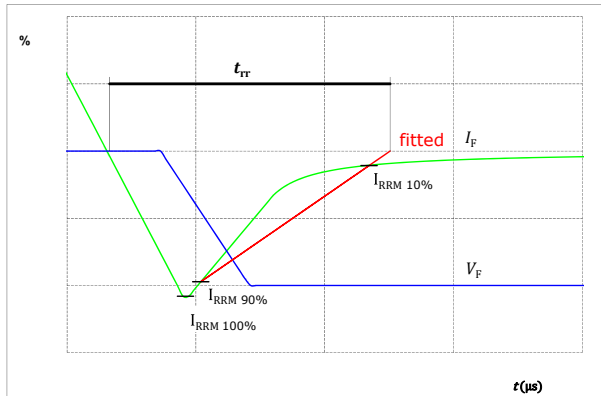
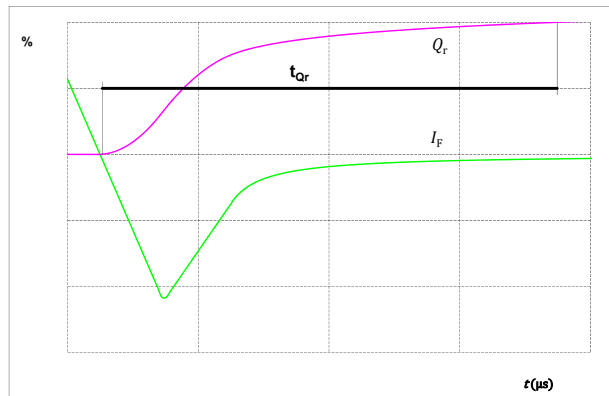


figure 30.

FWD

Turn-on Switching Waveforms & definition of t_{Qr} (t_{Qr} = integrating time for Q_r)





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datasheet

Ordering Code	
Version	Ordering Code
Without thermal paste	30-P2126PA140H7-L280F19Y
With thermal paste (5,2 W/mK, PTM6000HV)	30-P2126PA140H7-L280F19Y-/7/
With thermal paste (3,4 W/mK, PSX-P7)	30-P2126PA140H7-L280F19Y-/3/

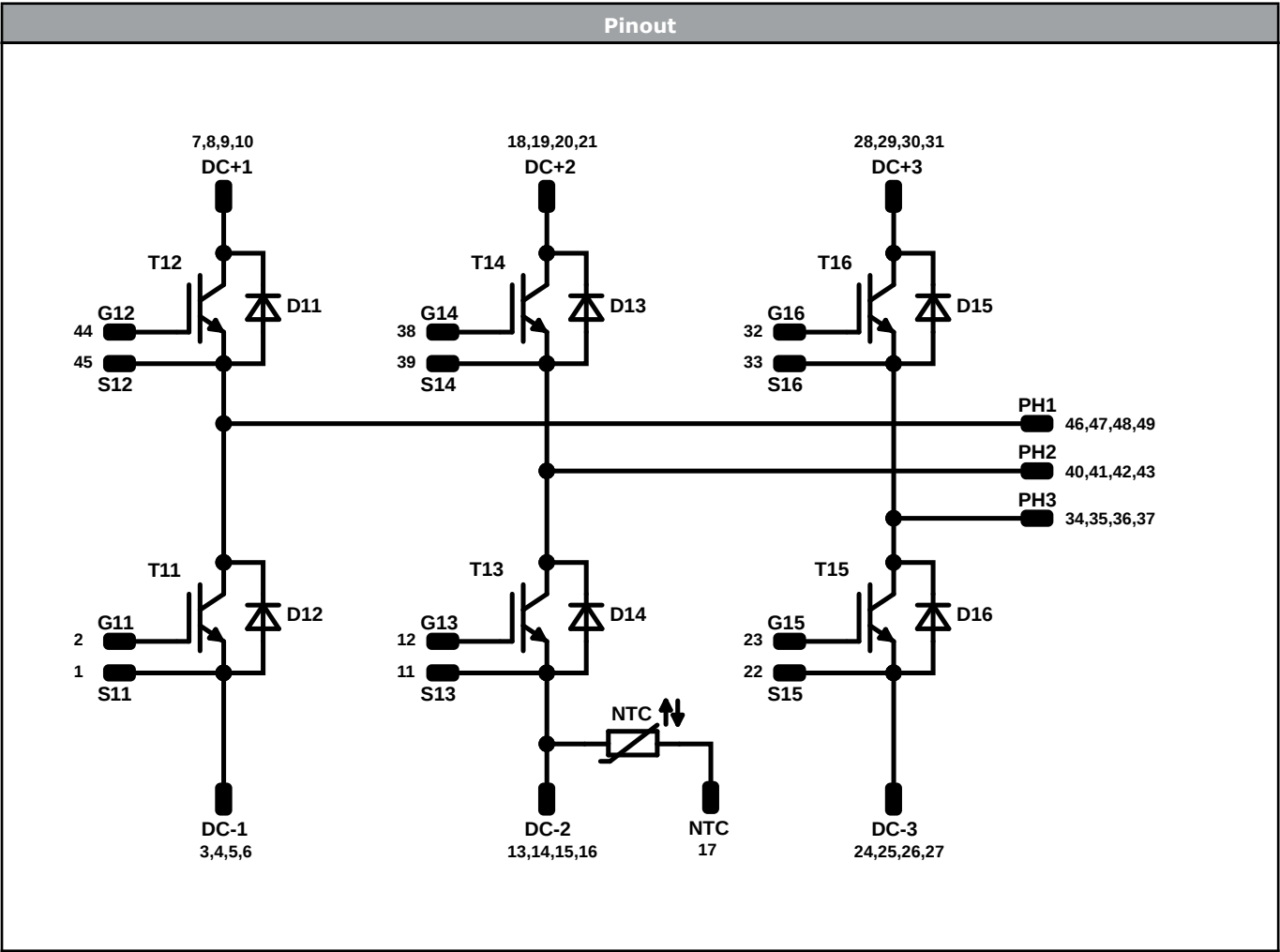
Marking							
	Text	Name NN-NNNNNNNNNNNNNN- TTTTTIV		Date code WWYY	UL & VIN UL VIN	Lot LLLLL	Serial SSSS
		Datamatrix	Type&Ver TTTTTTVV	Lot number LLLLL	Serial SSSS	Date code WWYY	

Outline							
Pin table [mm]							
Pin	X	Y	Function	26	54,5	5,4	DC-3
1	0,9	0	S11	27	57,2	0	DC-3
2	0,9	3	G11	28	65,8	0	DC+3
3	3,9	0	DC-1	29	65,8	2,7	DC+3
4	3,9	2,7	DC-1	30	68,5	0	DC+3
5	3,9	5,4	DC-1	31	68,5	2,7	DC+3
6	6,6	0	DC-1	32	64,7	36	G16
7	15,2	0	DC+1	33	61,7	36	S16
8	15,2	2,7	DC+1	34	58,7	36	PH3
9	17,9	0	DC+1	35	56	36	PH3
10	17,9	2,7	DC+1	36	53,3	36	PH3
11	26,2	0	S13	37	50,6	36	PH3
12	26,2	3	G13	38	39,4	36	G14
13	29,2	0	DC-2	39	36,4	36	S14
14	29,2	2,7	DC-2	40	33,4	36	PH2
15	29,2	5,4	DC-2	41	30,7	36	PH2
16	31,9	0	DC-2	42	28	36	PH2
17	32,2	4,05	NTC	43	25,3	36	PH2
18	40,5	0	DC+2	44	14,1	36	G12
19	40,5	2,7	DC+2	45	11,1	36	S12
20	43,2	0	DC+2	46	8,1	36	PH1
21	43,2	2,7	DC+2	47	5,4	36	PH1
22	51,5	0	S15	48	2,7	36	PH1
23	51,5	3	G15	49	0	36	PH1
24	54,5	0	DC-3				
25	54,5	2,7	DC-3				



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Identification					
ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	1200 V	140 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1200 V	140 A	Inverter Diode	
Rt	Thermistor			Thermistor	



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Packaging instruction				
Standard packaging quantity (SPQ) 36	>SPQ	Standard	<SPQ	Sample
Handling instruction				
Handling instructions for <i>flow 2</i> packages see vincotech.com website.				
Package data				
Package data for <i>flow 2</i> packages see vincotech.com website.				
Vincotech thermistor reference				
See Vincotech thermistor reference table at vincotech.com website.				
UL recognition and file number				
This device is UL 1557 recognized under E192116 up to a junction temperature under switching condition $T_{j,sp}=175^{\circ}\text{C}$ and up to 3500VAC/1min isolation voltage. For more information see vincotech.com website.				

Document No.:	Date:	Modification:	Pages
30-P2126PA140H7-L280F19Y-D1-14	8 Sep. 2026	Initial Release	

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.